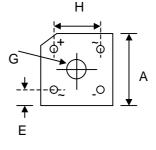


# **KBPC300 - KBPC310**

## 3.0A BRIDGE RECTIFIER

### **Features**

- Diffused Junction
- High Current Capability
- High Case Dielectric Strength
- High Surge Current Capability
- Ideal for Printed Circuit Board Application
- Plastic Material has Underwriters Laboratory Flammability Classification 94V-O
- UL Recognized File # E157705



KBPC-3								
Dim	Min Max							
Α	14.73	15.75						
В	5.84	6.86						
С	19.00	1						
D	0.70 Ø Typical							
Е	1.70	2.72						
G	Hole for #6 screw							
	3.60	4.00						
Н	10.30	11.30						
All Dimensions in mm								

#### **Mechanical Data**

Case: Molded Plastic

 Terminals: Plated Leads Solderable per MIL-STD-202, Method 208

Polarity: Marked on BodyWeight: 3.8 grams (approx.)

Mounting Position: Through Hole for #6 Screw
Mounting Torque: 5.0 Inch-pounds Maximum

Marking: Type Number

## Maximum Ratings and Electrical Characteristics @TA=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	S	Symbol	KBPC 300	KPBC 301	KBPC 302	KBPC 304	KBPC 306	KBPC 308	KBPC 310	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		VRRM VRWM VR	50	100	200	400	600	800	1000	٧
RMS Reverse Voltage		VR(RMS)	35	70	140	280	420	560	700	٧
Average Rectified Output Current (Note 1) @T <sub>C</sub> = 50°C		lo	3.0							Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)		IFSМ	50							А
Forward Voltage (per element) @I <sub>F</sub> = 1.5	5A	VFM	1.2					V		
Peak Reverse Current $@T_C = 25^\circ$ At Rated DC Blocking Voltage $@T_C = 100^\circ$		IR				10 1.0				μA mA
I <sup>2</sup> t Rating for Fusing (t<8.3ms) (Note 2)		l <sup>2</sup> t	10							A <sup>2</sup> s
Typical Junction Capacitance (Note 3)		Cj	55						pF	
Typical Thermal Resistance (Note 4)		RθJC	25						K/W	
Operating and Storage Temperature Range		Tj, Tstg	-65 to +125							°C

Note: 1. Mounted on metal chassis.

- 2. Non-repetitive, for t > 1ms and < 8.3ms.
- 3. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.
- 4. Thermal resistance junction to case per element.

